FEATURES

- DC - 3.125 Gbps Low Jitter, High Noise Immunity, Low Power Operation
- On-Chip 100 Ω Input and Output Termination Minimizes Insertion and Return Losses, Reduces Component Count and Minimizes Board Space
- 7 kV ESD on LVDS I/O Pins Protects Adjoining Components
- Small 3 mm x 3 mm WSON-8 Space Saving Package

APPLICATIONS

- Clock or Data Buffering / Repeating
- OC-48 / STM-16 Clock or Data Buffering / Repeating
- InfiniBand
- FireWire

DESCRIPTION

The DS25BR150 is a single channel 3.125 Gbps LVDS buffer optimized for high-speed signal transmission over printed circuit boards and balanced cables. Fully differential signal paths ensure exceptional signal integrity and noise immunity.

The DS25BR150 is a buffer/repeater with very low power consumption. Other LVDS devices with similar IO characteristics and with signal conditioning features include the following products. The DS25BR110 features four levels of equalization for use as an optimized receiver device, the DS25BR120 features four levels of pre-emphasis for use as an optimized driver device, and the DS25BR100 features both pre-emphasis and equalization for use as an optimized repeater device.

Wide input common mode range allows the receiver to accept signals with LVDS, CML and LVPECL levels; the output levels are LVDS. A very small package footprint requires a minimal space on the board while the flow-through pinout allows easy board layout. The differential inputs and outputs are internally terminated with a 100Ω resistor to lower device input and output return losses, reduce component count, and further minimize board space.

Typical Application

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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Block Diagram

Pin Diagram

<table>
<thead>
<tr>
<th>Pin Name</th>
<th>Pin Name</th>
<th>Pin Type</th>
<th>Pin Description</th>
</tr>
</thead>
<tbody>
<tr>
<td>NC</td>
<td>1</td>
<td>NA</td>
<td>&quot;NO CONNECT&quot; pin.</td>
</tr>
<tr>
<td>IN+</td>
<td>2</td>
<td>Input</td>
<td>Non-inverting LVDS input pin.</td>
</tr>
<tr>
<td>IN-</td>
<td>3</td>
<td>Input</td>
<td>Inverting LVDS input pin.</td>
</tr>
<tr>
<td>NC</td>
<td>4</td>
<td>NA</td>
<td>&quot;NO CONNECT&quot; pin.</td>
</tr>
<tr>
<td>NC</td>
<td>5</td>
<td>NA</td>
<td>&quot;NO CONNECT&quot; pin.</td>
</tr>
<tr>
<td>OUT-</td>
<td>6</td>
<td>Output</td>
<td>Inverting LVDS output pin.</td>
</tr>
<tr>
<td>OUT+</td>
<td>7</td>
<td>Output</td>
<td>Non-inverting LVDS Output pin.</td>
</tr>
<tr>
<td>VCC</td>
<td>8</td>
<td>Power</td>
<td>Power supply pin.</td>
</tr>
<tr>
<td>GND</td>
<td>DAP</td>
<td>Power</td>
<td>Ground pad (DAP - die attach pad)</td>
</tr>
</tbody>
</table>

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.
Absolute Maximum Ratings

- Supply Voltage (VCC) -0.3V to +4V
- LVDS Input Voltage (IN+, IN-) -0.3V to +4V
- Differential Input Voltage (VID) 1V
- LVDS Output Voltage (OUT+, OUT-) -0.3V to (VCC + 0.3V)
- LVDS Differential Output Voltage ((OUT+) - (OUT-)) 0V to 1V
- LVDS Output Short Circuit Current Duration 5 ms
- Junction Temperature +150 °C
- Storage Temperature Range -65 °C to +150 °C
- Lead Temperature Range Soldering (4 sec.) +260 °C
- Maximum Package Power Dissipation at 25 °C NGQ Package 2.08W
- Derate NGQ Package 16.7 mW/°C above +25 °C
- Package Thermal Resistance
  - θJA +60.0 °C/W
  - θJC +12.3 °C/W
- ESD Susceptibility
  - HBM (3) ≥7 kV
  - MM (4) ≥250V
  - CDM (5) ≥1250V

Notes:
1. “Absolute Maximum Ratings” indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions indicate conditions at which the device is functional and the device should not be operated beyond such conditions.
2. If Military/Aerospace specified devices are required, please contact the TI Sales Office/Distributors for availability and specifications.
3. Human Body Model, applicable std. JESD22-A114C
4. Machine Model, applicable std. JESD22-A115-A
5. Field Induced Charge Device Model, applicable std. JESD22-C101-C

Recommended Operating Conditions

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>Supply Voltage (VCC)</td>
<td>3.0</td>
<td>3.3</td>
<td>3.6</td>
<td>V</td>
</tr>
<tr>
<td>Receiver Differential Input Voltage (VID)</td>
<td>0</td>
<td>1</td>
<td></td>
<td>V</td>
</tr>
<tr>
<td>Operating Free Air Temperature (TA)</td>
<td>-40</td>
<td>+25</td>
<td>+85</td>
<td>°C</td>
</tr>
</tbody>
</table>

DC Electrical Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified. (1)(2)(3)

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>VOD</td>
<td>Differential Output Voltage</td>
<td>R_L = 100Ω</td>
<td>250</td>
<td>350</td>
<td>450</td>
<td>mV</td>
</tr>
<tr>
<td>ΔVOD</td>
<td>Change in Magnitude of VOD for Complimentary Output States</td>
<td>R_L = 100Ω</td>
<td>-35</td>
<td>35</td>
<td></td>
<td>mV</td>
</tr>
<tr>
<td>VOS</td>
<td>Offset Voltage</td>
<td>R_L = 100Ω</td>
<td>1.05</td>
<td>1.2</td>
<td>1.375</td>
<td>V</td>
</tr>
<tr>
<td>ΔVOS</td>
<td>Change in Magnitude of VOS for Complimentary Output States</td>
<td>R_L = 100Ω</td>
<td>-35</td>
<td>35</td>
<td></td>
<td>mV</td>
</tr>
<tr>
<td>IOS</td>
<td>Output Short Circuit Current(4)</td>
<td>OUT to GND</td>
<td>-25</td>
<td>-50</td>
<td></td>
<td>mA</td>
</tr>
<tr>
<td></td>
<td></td>
<td>OUT to VCC</td>
<td>7.5</td>
<td>50</td>
<td></td>
<td>mA</td>
</tr>
<tr>
<td>COUT</td>
<td>Output Capacitance</td>
<td>Any LVDS Output Pin to GND</td>
<td>1.2</td>
<td></td>
<td></td>
<td>pF</td>
</tr>
<tr>
<td>ROUT</td>
<td>Output Termination Resistor</td>
<td>Between OUT+ and OUT-</td>
<td>100</td>
<td></td>
<td></td>
<td>Ω</td>
</tr>
</tbody>
</table>

Notes:
1. The Electrical Characteristics tables list ensured specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not ensured.
2. Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except VOD and ΔVOD.
3. Typical values represent most likely parametric norms for VCC = +3.3V and TA = +25 °C, and at the Recommended Operation Conditions at the time of product characterization and are not ensured.
4. Output short circuit current (IOS) is specified as magnitude only, minus sign indicates direction only.
### DC Electrical Characteristics (continued)

Over recommended operating supply and temperature ranges unless otherwise specified.\(^{(1)(2)(3)}\)

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>(V_{ID})</td>
<td>Input Differential Voltage</td>
<td></td>
<td>0</td>
<td>1</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>(V_{TH})</td>
<td>Differential Input High Threshold</td>
<td>(V_{CM} = +0.05)V or (V_{CC} - 0.05)V</td>
<td>0</td>
<td>+100</td>
<td>mV</td>
<td></td>
</tr>
<tr>
<td>(V_{TL})</td>
<td>Differential Input Low Threshold</td>
<td></td>
<td>-100</td>
<td>0</td>
<td>mV</td>
<td></td>
</tr>
<tr>
<td>(V_{CMR})</td>
<td>Common Mode Voltage Range</td>
<td>(V_{ID} = 100)mV</td>
<td>0.05</td>
<td>(V_{CC} - 0.05)</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>(I_{IN})</td>
<td>Input Current</td>
<td>(V_{IN} = 3.6)V or 0V</td>
<td>(\pm 1)</td>
<td>(\pm 10)</td>
<td>(\mu A)</td>
<td></td>
</tr>
<tr>
<td>(C_{IN})</td>
<td>Input Capacitance</td>
<td>Any LVDS Input Pin to GND</td>
<td>1.7</td>
<td></td>
<td>pF</td>
<td></td>
</tr>
<tr>
<td>(R_{IN})</td>
<td>Input Termination Resistor</td>
<td>Between (IN^+) and (IN^-)</td>
<td>100</td>
<td></td>
<td>(\Omega)</td>
<td></td>
</tr>
</tbody>
</table>

### SUPPLY CURRENT

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
<th>Conditions</th>
<th>Min</th>
<th>Typ</th>
<th>Max</th>
<th>Units</th>
</tr>
</thead>
<tbody>
<tr>
<td>(I_{CC})</td>
<td>Supply Current</td>
<td></td>
<td>27</td>
<td>35</td>
<td>mA</td>
<td></td>
</tr>
</tbody>
</table>

### AC Electrical Characteristics\(^{(1)}\)

Over recommended operating supply and temperature ranges unless otherwise specified.\(^{(2)(3)}\)

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
</tr>
</thead>
<tbody>
<tr>
<td>(I_{PHL,H})</td>
<td>Differential Propagation Delay High to Low</td>
</tr>
<tr>
<td>(I_{PLHD})</td>
<td>Differential Propagation Delay Low to High</td>
</tr>
<tr>
<td>(I_{SKD1})</td>
<td>Pulse Skew</td>
</tr>
<tr>
<td>(I_{SKD2})</td>
<td>Part to Part Skew</td>
</tr>
<tr>
<td>(I_{LHT})</td>
<td>Rise Time</td>
</tr>
<tr>
<td>(I_{HLT})</td>
<td>Fall Time</td>
</tr>
</tbody>
</table>

### JITTER PERFORMANCE (Figure 5)

<table>
<thead>
<tr>
<th>Symbol</th>
<th>Parameter</th>
</tr>
</thead>
<tbody>
<tr>
<td>(I_{DJ,1})</td>
<td>Deterministic Jitter (Peak-to-Peak Value)</td>
</tr>
<tr>
<td>(I_{DJ,2})</td>
<td>Random Jitter (RMS Value)</td>
</tr>
<tr>
<td>(I_{DJ,1})</td>
<td>Total Jitter (Peak to Peak Value)</td>
</tr>
</tbody>
</table>

\(^{(1)}\) Specification is ensured by characterization and is not tested in production.
\(^{(2)}\) The Electrical Characteristics tables list ensured specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not ensured.
\(^{(3)}\) Typical values represent most likely parametric norms for \(V_{CC} = +3.3\)V and \(T_A = +25^\circ C\), and at the Recommended Operation Conditions at the time of product characterization and are not ensured.
\(^{(4)}\) \(I_{SKD1} = I_{PLHD} - I_{PHLD}\), is the magnitude difference in differential propagation delay time between the positive going edge and the negative going edge of the same channel.
\(^{(5)}\) \(I_{SKD2}\), Part to Part Skew, is defined as the difference between the minimum and maximum specified differential propagation delays. This specification applies to devices at the same \(V_{CC}\) and within \(5^\circ C\) of each other within the operating temperature range.
\(^{(6)}\) Tested with a combination of the 1100000101 (K28.5+ character) and 0011111010 (K28.5- character) patterns. Input stimulus jitter is subtracted algebraically.
\(^{(7)}\) Measured on a clock edge with a histogram and an accumulation of 1500 histogram hits. Input stimulus jitter is subtracted geometrically.
\(^{(8)}\) Measured on an eye diagram with a histogram and an accumulation of 3500 histogram hits. Input stimulus jitter is subtracted.
DC TEST CIRCUITS

Figure 1. Differential Driver DC Test Circuit

AC Test Circuits and Timing Diagrams

Figure 2. Differential Driver AC Test Circuit

Figure 3. Propagation Delay Timing Diagram

Figure 4. LVDS Output Transition Times

Figure 5. Jitter Measurements Test Circuit
Device Operation

INPUT INTERFACING

The DS25BR150 accepts differential signals and allows simple AC or DC coupling. With a wide common mode range, the DS25BR150 can be DC-coupled with all common differential drivers (i.e. LVPECL, LVDS, CML). The following three figures illustrate typical DC-coupled interface to common differential drivers. Note that the DS25BR150 inputs are internally terminated with a 100Ω resistor.

Figure 6. Typical LVDS Driver DC-Coupled Interface to DS25BR150 Input

Figure 7. Typical CML Driver DC-Coupled Interface to DS25BR150 Input

Figure 8. Typical LVPECL Driver DC-Coupled Interface to DS25BR150 Input

OUTPUT INTERFACING

The DS25BR150 outputs signals are compliant to the LVDS standard. It can be DC-coupled to most common differential receivers. The following figure illustrates typical DC-coupled interface to common differential receivers and assumes that the receivers have high impedance inputs. While most differential receivers have a common mode input range that can accommodate LVDS compliant signals, it is recommended to check the respective receiver’s data sheet prior to implementing the suggested interface implementation.
Figure 9. Typical DS25BR150 Output DC-Coupled Interface to an LVDS, CML or LVPECL Receiver
Typical Performance Characteristics

Figure 10. A 2.5 Gbps NRZ PRBS-7 Output Eye Diagram  
V:100 mV / DIV, H:75 ps / DIV

Figure 11. Total Jitter as a Function of Input Amplitude
V:100 mV / DIV, H:50 ps / DIV

Figure 12. A 3.125 Gbps NRZ PRBS-7 Output Eye Diagram  
V:100 mV / DIV, H:50 ps / DIV

Figure 13. Total Jitter as a Function of Input Amplitude
## REVISION HISTORY

### Changes from Revision D (April 2013) to Revision E

<table>
<thead>
<tr>
<th>Change Description</th>
<th>Page</th>
</tr>
</thead>
<tbody>
<tr>
<td>Changed layout of National Data Sheet to TI format</td>
<td>8</td>
</tr>
</tbody>
</table>
# PACKAGE OPTION ADDENDUM

## PACKAGING INFORMATION

<table>
<thead>
<tr>
<th>Orderable Device</th>
<th>Status</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>Package Qty</th>
<th>Eco Plan (2)</th>
<th>Lead/Ball Finish (6)</th>
<th>MSL Peak Temp (3)</th>
<th>Op Temp (°C)</th>
<th>Device Marking (4/5)</th>
<th>Samples</th>
</tr>
</thead>
<tbody>
<tr>
<td>DS25BR150TSD/NOPB</td>
<td>ACTIVE</td>
<td>WSON</td>
<td>NGQ</td>
<td>8</td>
<td>1000</td>
<td>Green (RoHS &amp; no Sb/Br)</td>
<td>SN</td>
<td>Level-3-260C-168 HR</td>
<td>-40 to 85</td>
<td>2R150</td>
<td></td>
</tr>
</tbody>
</table>

(1) The marketing status values are defined as follows:

**ACTIVE**: Product device recommended for new designs.
**LIFEBUY**: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
**NRND**: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.
**OBsolete**: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt**: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green**: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "---" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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**TAPE AND REEL INFORMATION**

### TAPE DIMENSIONS

- **A0**: Dimension designed to accommodate the component width
- **B0**: Dimension designed to accommodate the component length
- **K0**: Dimension designed to accommodate the component thickness
- **W**: Overall width of the carrier tape
- **P1**: Pitch between successive cavity centers

### REEL DIMENSIONS

- Reel Diameter
- Reel Width (W1)

### Quadrant Assignments for Pin 1 Orientation in Tape

- Q1
- Q2
- Q3
- Q4

---

*All dimensions are nominal*

<table>
<thead>
<tr>
<th>Device</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>SPQ</th>
<th>Reel Diameter (mm)</th>
<th>Reel Width W1 (mm)</th>
<th>A0 (mm)</th>
<th>B0 (mm)</th>
<th>K0 (mm)</th>
<th>P1 (mm)</th>
<th>W (mm)</th>
<th>Pin1 Quadrant</th>
</tr>
</thead>
<tbody>
<tr>
<td>DS25BR150TSD/NOPB</td>
<td>WSON</td>
<td>NGQ</td>
<td>8</td>
<td>1000</td>
<td>178.0</td>
<td>12.4</td>
<td>3.3</td>
<td>3.3</td>
<td>1.0</td>
<td>8.0</td>
<td>12.0</td>
<td>Q1</td>
</tr>
</tbody>
</table>

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www.ti.com 20-Sep-2016
**TAPE AND REEL BOX DIMENSIONS**

*All dimensions are nominal

<table>
<thead>
<tr>
<th>Device</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>SPQ</th>
<th>Length (mm)</th>
<th>Width (mm)</th>
<th>Height (mm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>DS25BR150TSD/NOPB</td>
<td>WSON</td>
<td>NGQ</td>
<td>8</td>
<td>1000</td>
<td>210.0</td>
<td>185.0</td>
<td>35.0</td>
</tr>
</tbody>
</table>
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.
NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
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